Application No.: 10/606,964 Docket No.: 22040-00016-US1

AMENDMENTS TO THE CLAIMS

This listing of claims replaces all previous versions and listings of claims in this application:

Claims 1-4 (Canceled).

5. (Currently amended) An amplifier circuit for AM broadcasting for amplifying an inputted AM broadcast signal suitable for amplifying an AM broadcast signal, the circuit comprising:

by FETs and outputting it, characterized in that said FETs include

a first P-channel MOSFET for amplifying said which amplifies the inputted AM broadcast signal; and

a second P-channel MOSFET for AGC-controlling the which controls a gain of a signal outputted from said first P-channel MOSFET;

wherein said first P-channel MOSFET and said second P-channel MOSFET are cascode-coupled in a manner which ensures that a flicker noise level of the amplifier circuit is intermediate to respective flicker noise levels of a JFET-configured circuit and an N-MOS configured circuit.

- 6. (Currently amended) An amplifier circuit for AM broadcasting, characterized by suitable for amplifying an AM broadcast signal, the circuit comprising:
- a first P-channel MOSFET for amplifying an inputted which amplifies the AM broadcast signal;
- a second P-channel MOSFET for AGC-controlling the connected to the first P-channel MOSFET, said second P-channel MOSFET controlling a gain of a signal outputted from said first P-channel MOSFET; and

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a tuning circuit connected to a drain of the second P-channel MOSFET, said tuning circuit for high-frequency amplifying the signal outputted filtering and providing an output from said second P-channel MOSFET and outputting it;

wherein said first P-channel MOSFET and said second P-channel MOSFET are configured in a cascode-coupled arrangement which reduces a flicker noise of the amplifier circuit below a flicker noise level of an equivalent N-MOS configured circuit.

- 7. (Currently amended) An amplifier circuit for AM broadcasting, characterized by suitable for amplifying an AM broadcast signal, the circuit comprising:
- a capacitor for cutting which blocks a DC component of an inputted the AM broadcast signal;
- a first P-channel MOSFET for amplifying connected to an output of the capacitor, said first P-channel MOSFET amplifying the AM broadcast signal-outputted from said-capacitor;
 - a resistor for giving said-which biases the first P-channel MOSFET-an appropriate bias;
- a second P-channel MOSFET for AGC-controlling the connected to the first P-channel MOSFET so as to control a gain of a signal outputted from said first P-channel MOSFET; and
- a tuning circuit for high frequency amplifying which filters and outputs the signal outputted from said second P-channel MOSFET and outputting it;

wherein said first P-channel MOSFET and said second P-channel MOSFET are configured in a cascode-coupled arrangement which reduces a flicker noise of the amplifier circuit below a flicker noise level of an equivalent N-MOS configured circuit.

8. (Currently amended) The amplifier circuit for AM broadcasting according to of claim 5, characterized in that the wherein a channel area of said P-channel MOSFET is greater than a predetermined value selected to reduce a flicker noise of the amplifier circuit.

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9. (Currently amended) The amplifier circuit for AM broadcasting according to of claim 6, characterized in that the wherein a channel area of said P-channel MOSFET is greater than a predetermined value selected to reduce a flicker noise of the amplifier circuit.

- 10. (Currently amended) The amplifier circuit for AM broadcasting according to of claim 7, characterized in that the wherein a channel area of said P-channel MOSFET is greater than a predetermined value selected to reduce a flicker noise of the amplifier circuit.
- 11. (New) An amplifier circuit suitable for amplifying an AM broadcast signal, the circuit comprising:

FET means for amplifying the AM broadcast signal and reducing a flicker noise level in the amplifier below an N-MOS transistor equivalent flicker noise; and

a tuning circuit operatively connected between the FET means and an output node of the amplifier circuit.

- 12. (New) The amplifier circuit of claim 11, wherein said FET means comprises two cascode-coupled P-MOS transistors.
- 13. (New) The amplifier circuit of claim 11, wherein said FET means comprises two cascode-coupled P-MOS transistors which receive, respectively, the AM broadcast signal and an AGC voltage.
- 14. (New) The amplifier circuit of claim 11, further comprising a DC-blocking capacitor,

wherein the AM broadcast signal is coupled through the DC-blocking capacitor to the FET means at a gate of a P-MOS transistor contained therein.